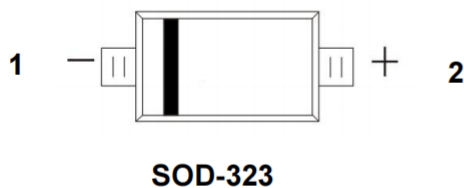


Features

- Repetitive peak forward current
- High switching speed
- Continuous reverse voltage
- Repetitive peak reverse voltage



Applications

- High-speed switching
- General-purpose switching
- Polarity protection application
- Freewheeling diodes



Absolute Maximum Ratings (TA=25°C unless otherwise specified)

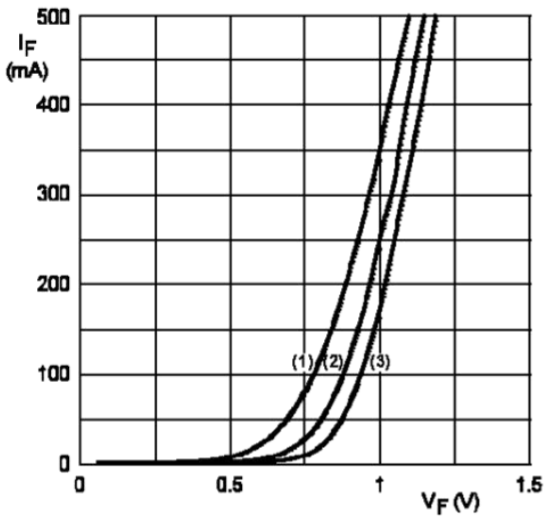
Parameter	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	300	V
Peak Repetitive Peak Reverse Voltage	V _{RRM}	300	V
Power Dissipation	PD	200	mW
Average Forward Current	I _F	225	mA
Peak Forward Surge Current @t=8.3ms	I _{FSM}	625	mA
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55~+150	°C
Thermal Resistance from Junction to Ambient	R _{θJA}	667	°C/W

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Forward Voltage	V _F	I _F = 1mA	--	0.6	--	V
		I _F = 10mA	--	0.7	--	V
		I _F = 50mA	--	0.8	--	V
		I _F = 100mA	--	--	1.1	V
Maximum Peak Reverse Current	I _R	V _R = 250V	--	--	150	nA
		V _R = 100V	--	50	--	nA
Reverse Breakdown Voltage	V _{BR}	I _R = 100μA	300	--	--	V
Total Capacitance	C _J	V _R = 0V, f = 1.0MHz	--	--	5	pF
Reverse Recovery Time	t _{rr}	I _F = I _R = 30mA, I _{rr} = 1mA, R _L = 100Ω	--	--	50	ns

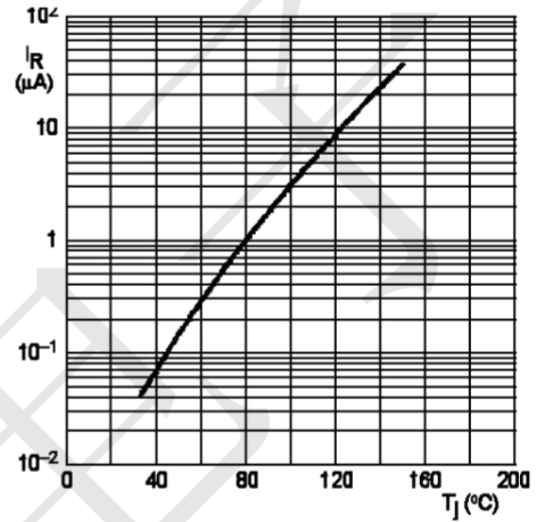
Note 1: The data tested by surface mounted on a 18mm * 15mm * 1mm FR4-epoxy P.C.B

Typical Electrical Characteristic Curves



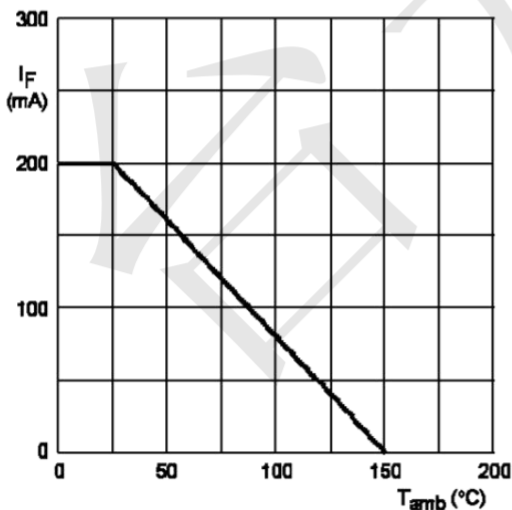
- (1) $T_{amb} = 150\text{ }^{\circ}\text{C}$.
- (2) $T_{amb} = 75\text{ }^{\circ}\text{C}$.
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}$.

Forward current as a function of forward voltage; typical values.

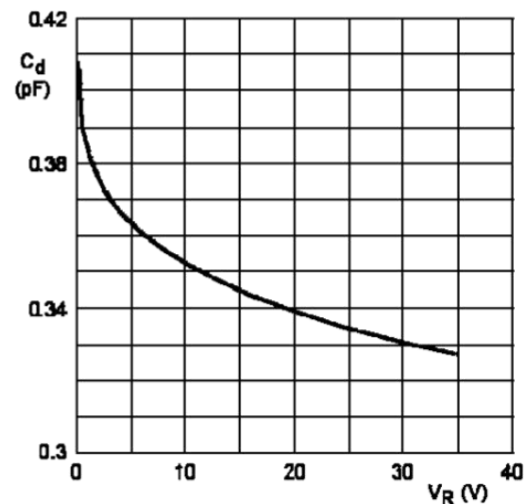


$V_R = V_{Rmax}$; typical values.

Reverse current as a function of junction temperature.



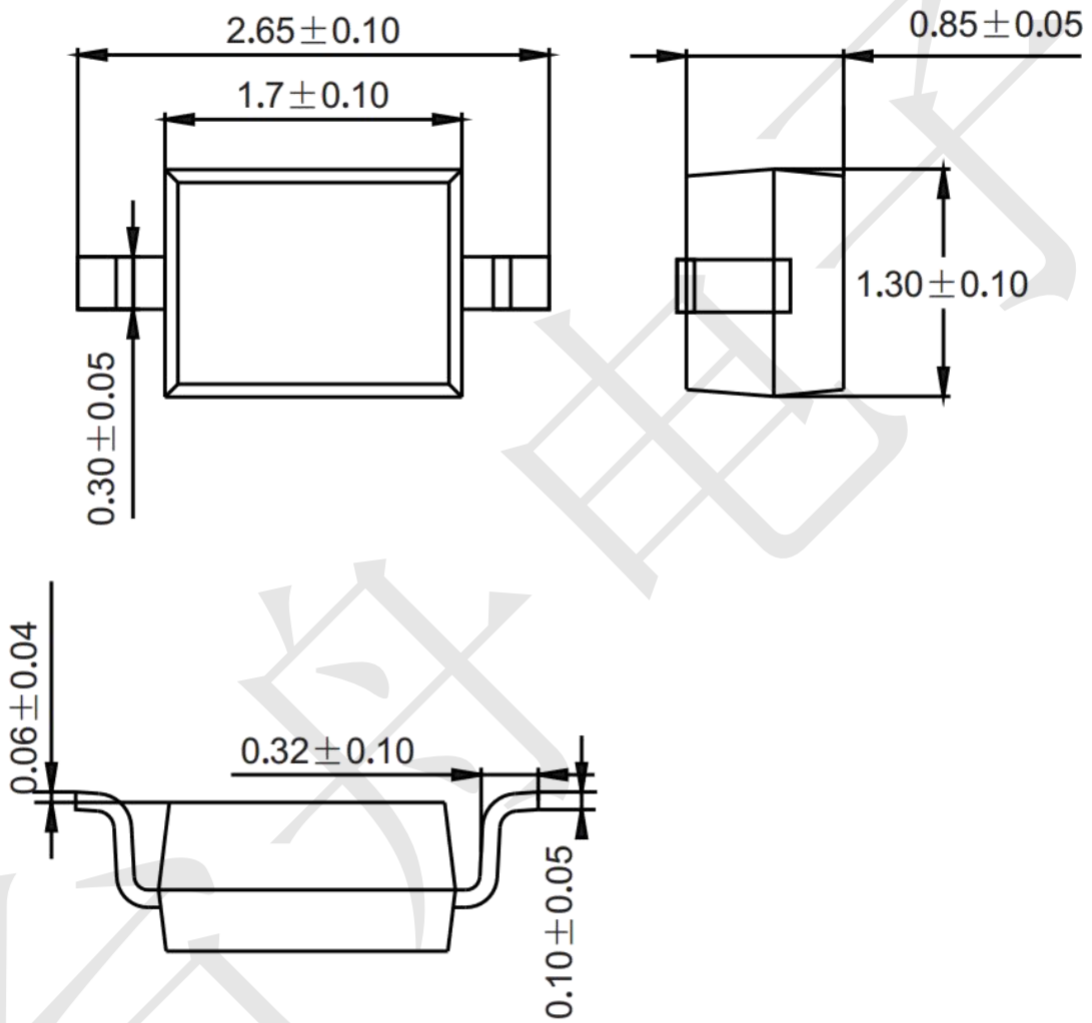
Maximum permissible continuous forward current as a function of ambient temperature.



Diode capacitance as a function of reverse voltage; typical values.

Package Outline Dimensions (unit: mm)

SOD-323



Mounting Pad Layout (unit: mm)

